

RCX051N25

RCX051N25 Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RCX051N25 Specifications

Manufacturer Part Number	RCX051N25
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-2 Full Pack
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	250V
Current - Continuous Drain (Id) @ 25°C	5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	8.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	350pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	2.23W (Ta), 30W (Tc)
Rds On (Max) @ Id, Vgs	1.36 Ohm @ 2.5A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220FM
Package / Case	TO-220-2 Full Pack
	Report errors?

RCX051N25 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

If you have any question about RCX051N25, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com